Due Date: January 2, 2008

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Benjamin A. Haskell et al.

Examiner:

Michael P. Lulis

Scrial No.:

10/537,385

Group Art Unit:

2824

Filed:

June 3, 2005

Docket:

G&C 30794.94-US-WO

Title:

GROWTH OF PLANAR, NON-POLAR GALLIUM NITRIDE BY HIDRIDE

VAPOR PHASE EPITAXY

CERTIFICATE OF MAILING OR TRANSMISSION UNDER 37 CFR 1.8

I hereby certify that this correspondence is being filed via facsimile transmission to the U.S. Patent and Trademark Office on January 2, 2008.

Name: Christine Flores

<u>PETITION FOR EXTENSION OF TIME</u>

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir.

In accordance with the provisions of 37 C.F.R. §1.136(a), it is respectfully requested that a three-month extension of time be granted in which to respond to the outstanding Office Action mailed July 2, 2007, said period of response being extended from October 2, 2007 to January 2, 2008.

Please charge the required extension fee in the amount of \$1,050.00 for a large entity to Deposit Account No. 50-0494.

Respectfully submitted,

GATES & COOPER LLP

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